NSN 5961-01-413-4358

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-413-4358 **Inclosure Material:** Metal or glass **Overall Length:** 0.155 inches **Terminal Length:** 0.975 inches **Overall Diameter:** 0.070 inches **Mounting Method:** Terminal **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 200.0 breakdown voltage, dc **Power Rating Per Characteristic:** 25000.0 watts small-signal input power, common-collector absolute **Capacitance Rating In Picofarads:** 0.5 **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Precious Material And Location:** Terminals silver **Test Data Document:** 19564-2738741 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**